## SN74ALS29827, SN74ALS29828 10-BIT BUFFERS AND BUS DRIVERS WITH 3-STATE OUTPUTS

SDAS095B - JANUARY 1986 - REVISED JANUARY 1995

<ul> <li>Functionally Equivalent to AMD's AM29827 and AM29828</li> </ul>	DW OR NT PACKAG (TOP VIEW)	ε
<ul> <li>3-State Outputs Drive Bus Lines or Buffer Memory Address Registers</li> </ul>	OE1 1 24 V A1 2 23 Y	CC
• pnp Inputs Reduce dc Loading	A1 12 23 1 A2 3 22 Y	•
<ul> <li>Data Flow-Through Pinout (All Inputs on</li> </ul>	A3 [ 4 21 ] Y	
Opposite Side From Outputs)	A4 🛛 5 20 🛛 Y	<b>′</b> 4
Power-Up High-Impedance State	A5 🛛 6 19 🗍 Y	′5
Package Options Include Plastic	A6 🛛 7 18 🛛 Y	
Small-Outline (DW) Packages and Standard	A7 🛛 8 17 🛛 Y	
Plastic (NT) 300-mil DIPs	A8 9 16 Y	′8
	A9 🛛 10 15 🗍 Y	-
description	A10 🛛 11 🛛 14 🗍 Y	′10
These 10-bit buffers and bus drivers provide	GND [ 12 13 ] C	DE2

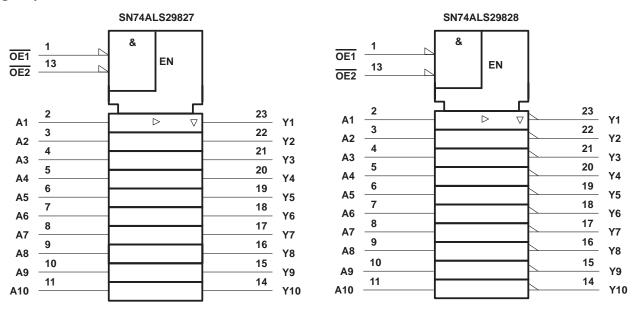
These 10-bit buffers and bus drivers provide high-performance bus interface for wide data paths or buses carrying parity.

The 3-state control gate is a 2-input NOR such that if either output-enable ( $\overline{OE1}$  or  $\overline{OE2}$ ) input is high, all ten outputs are in the high-impedance state.

The SN74ALS29827 provides true data and the SN74ALS29828 provides inverted data at their respective outputs.

The SN74ALS29827 and SN74ALS29828 are characterized for operation from 0°C to 70°C.

#### logic symbols<sup>†</sup>



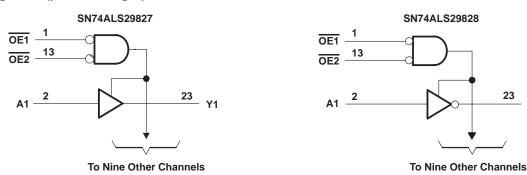
<sup>†</sup> These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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#### logic diagrams (positive logic)



#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage, V <sub>CC</sub>	7 V
Input voltage, V <sub>1</sub>	5.5 V
Voltage applied to a disabled 3-state output	5.5 V
Operating free-air temperature range, T <sub>A</sub> 0°	C to 70°C
Storage temperature range	; to 150°C

23

Y1

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### recommended operating conditions

		SN74ALS29827 SN74ALS29828			UNIT
		MIN	NOM	MAX	
Vcc	Supply voltage	4.75	5	5.25	V
VIH	High-level input voltage	2			V
VIL	Low-level input voltage			0.8	V
IOH	High-level output current			-24	mA
IOL	Low-level output current			48	mA
ТА	Operating free-air temperature	0		70	°C



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# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CC	ONDITIONS	SN74ALS29827 SN74ALS29828		-	UNIT	
			MIN	ΤΥΡ <sup>†</sup> ΜΑΧ			
VIK	V <sub>CC</sub> = 4.75 V,	lj = -18 mA			-1.2	V	
Varia		I <sub>OH</sub> = -15 mA	2.4			v	
Vон	V <sub>CC</sub> = 4.75 V	$I_{OH} = -24 \text{ mA}$	2		Ň		
VOL	V <sub>CC</sub> = 4.75 V,	I <sub>OL</sub> = 48 mA		0.35	0.5	V	
IOZH	V <sub>CC</sub> = 5.25 V,	V <sub>O</sub> = 2.4 V			20	μΑ	
I <sub>OZL</sub>	V <sub>CC</sub> = 5.25 V,	V <sub>O</sub> = 0.4 V			-20	μΑ	
lj	V <sub>CC</sub> = 5.25 V,	V <sub>I</sub> = 5.5 V			0.1	mA	
IН	V <sub>CC</sub> = 5.25 V,	V <sub>I</sub> = 2.7 V			20	μΑ	
۱ <sub>IL</sub>	V <sub>CC</sub> = 5.25 V,	V <sub>I</sub> = 0.4 V			-0.1	mA	
los‡	V <sub>CC</sub> = 5.25 V,	V <sub>O</sub> = 0	-75		-250	mA	
ICC	V <sub>CC</sub> = 5.25 V			25	40	mA	

<sup>†</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

<sup>‡</sup>Not more than one output should be shorted at a time, and the duration of the short circuit should not exceed one second.

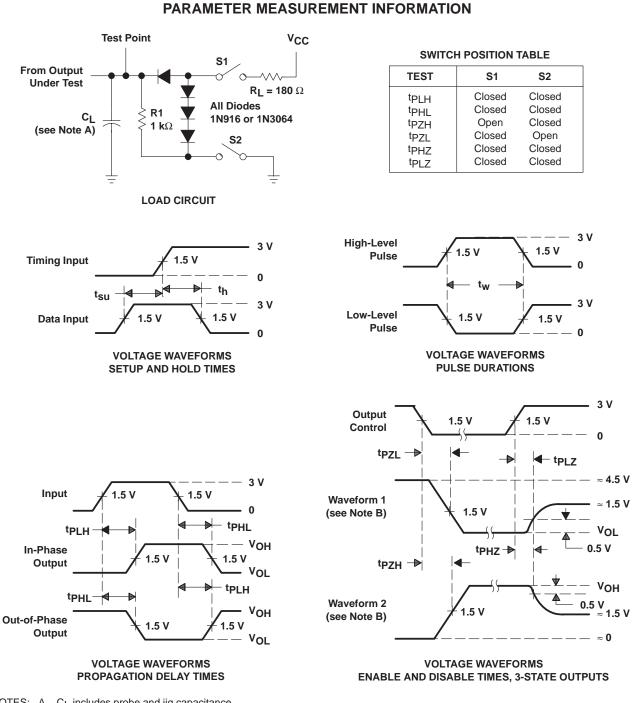
### switching characteristics (see Figure 1)

			TO (OUTPUT) TEST CONDITIONS	V <sub>CC</sub> = 4.75		
PARAMETER	FROM (INPUT)			SN74ALS29827	SN74ALS29828	UNIT
				MIN MAX	MIN MAX	
<sup>t</sup> PLH	А	X	0 000 - 5	15	14	ns
<sup>t</sup> PHL	A	Y	C <sub>L</sub> = 300 pF	15	14	115
<sup>t</sup> PLH	А	V	0 50 - 5	8	7	ns
<sup>t</sup> PHL	A	Y	C <sub>L</sub> = 50 pF	8	7.5	115
<sup>t</sup> PZH		V	0 000 - 5	20	20	ns
<sup>t</sup> PZL	OE	Y	C <sub>L</sub> = 300 pF	23	23	115
<sup>t</sup> PZH	OE	Y	0 50 - 5	15	15	ns
t <sub>PZL</sub>	OE	ř	C <sub>L</sub> = 50 pF	15	15	115
<sup>t</sup> PHZ	OE	Y	0. 50 - 5	17	17	ns
<sup>t</sup> PLZ	UE	ř	C <sub>L</sub> = 50 pF	12	12	115
<sup>t</sup> PHZ	OE	Y	C <sub>L</sub> = 5 pF	9	9	ns
<sup>t</sup> PLZ	UE	r	CL = 5 PF	9	9	115



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NOTES: A. CL includes probe and jig capacitance.

Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Β. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>f</sub>  $\leq$  2.5 ns, t<sub>f</sub>  $\leq$  2.5 ns.

Figure 1. Load Circuit and Voltage Waveforms



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